TOSHIBA 2SD2131

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE (DARLINGTON)

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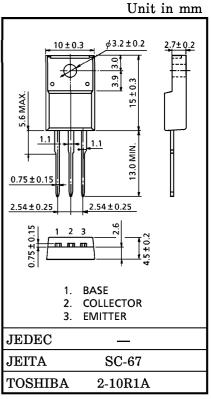
HIGH POWER SWITCHING APPLICATIONS

HAMMER DRIVE, PULSE MOTOR DRIVE APPLICATIONS

- High DC Current Gain
 - : $h_{FE} = 2000$ (Min.) ($V_{CE} = 3V$, $I_{C} = 3A$)
- Low Saturation Voltage
 - : $V_{CE (sat)} = 1.5V (Max.) (I_C = 3A)$
- Zener Diode Included Between Collector and Base.
- Unclamped Inductive Load Energy: E=150mJ (Min.)

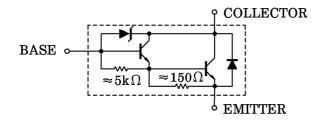
MAXIMUM RATINGS (Tc = 25°C)

| CHARACTERISTIC | | SYMBOL | RATING | UNIT | |
|---------------------------|--------------------|--------------------|---------|------|--|
| Collector-Base Voltage | | v_{CBO} | 60±10 | V | |
| Collector-Emitter Voltage | | v_{CEO} | 60±10 | V | |
| Emitter-Base Voltage | | $V_{ m EBO}$ | 7 | V | |
| Callanton Command | DC | $_{ m IC}$ | 5 | A | |
| Collector Current | Pulse | I_{CP} | 8 | | |
| Base Current | $I_{\mathbf{B}}$ | 0.5 | A | | |
| Collector Power | $Ta = 25^{\circ}C$ | D | 2.0 | w | |
| Dissipation | $Tc = 25^{\circ}C$ | $^{\mathrm{PC}}$ | 30 | | |
| Junction Temperature | | T_{j} | 150 | °C | |
| Storage Temperature Range | | $\mathrm{T_{stg}}$ | -55~150 | °C | |
| | | | | | |



Weight: 1.7g (Typ.)

EQUIVALENT CIRCUIT

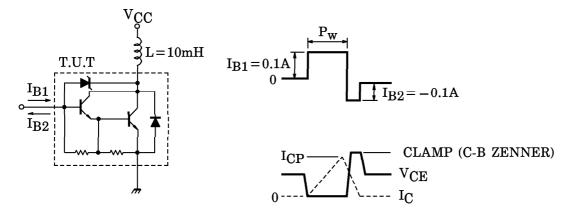


1 2001-11-05

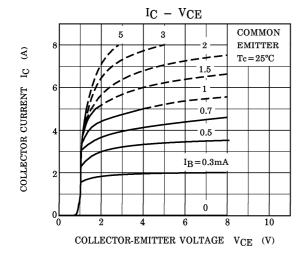
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

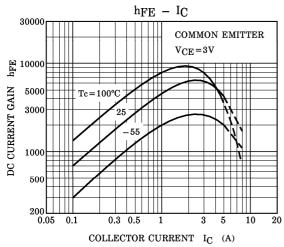
| CHARACTERISTIC | | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT | |
|---|---------------------|---------------------------|--|------|-------|------|---------|--|
| Collector Cut- | off Current | I_{CBO} | $V_{CB} = 45V, I_{E} = 0$ | | _ | 10 | μ A | |
| Collector Cut- | off Current | I _{CEO} | $V_{CE} = 45V, I_B = 0$ | | _ | 10 | μ A | |
| Emitter Cut-of | ff Current | I_{EBO} | $V_{EB}=6V, I_{C}=0$ | _ | _ | 2.5 | mA | |
| Collector-Base Breakdown Voltage | | V (BR) CBO | $I_{\rm C} = 1$ mA, $I_{\rm E} = 0$ | 50 | 60 | 70 | V | |
| Collector-Emit Voltage | ter Breakdown | V (BR) CEO | $I_{C}=10mA, I_{B}=0$ | 50 | 60 | 70 | V | |
| DC Current Gain | h _{FE (1)} | $V_{CE}=3V, I_{C}=3A$ | 2000 | _ | 15000 | | | |
| DC Current Gain | | h _{FE} (2) | $V_{CE}=3V, I_{C}=5A$ | 1000 | _ | _ | | |
| Collector-Emitter Saturation Voltage | | V _{CE} (sat) (1) | $I_C=3A$, $I_B=6mA$ | _ | 1.1 | 1.5 | V | |
| | | | $I_C=5A$, $I_B=20mA$ | _ | 1.3 | 2.5 | | |
| Base-Emitter S Voltage | Saturation | V _{BE} (sat) | $I_{\rm C}$ =3A, $I_{\rm B}$ =6mA | _ | 1.7 | 2.5 | V | |
| Unclamped In Energy | ductive Load | E _{S/B} | (Note 1) | 150 | _ | _ | mJ | |
| Switching Time Storage | Turn-on Time | ton | IB1 PUT IB2 | | 1.0 | _ | | |
| | Storage Time | ${ m t_{stg}}$ | | _ | 4.0 | _ | μs | |
| | Fall Time | tf | $ \begin{array}{ll} I_{B1}\!=\!-I_{B2}\!=\!6\text{mA}, & \text{V}_{CC} \\ \text{DUTY CYCLE}\!\leq\!1\% & =\!30\text{V} \end{array} $ | 1 | 2.5 | _ | ı | |

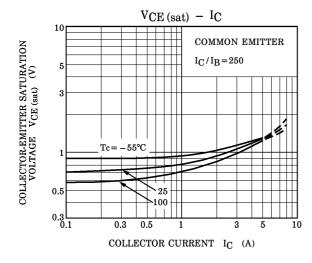
(Note 1) Measurement circuit of unclamped inductive load energy.

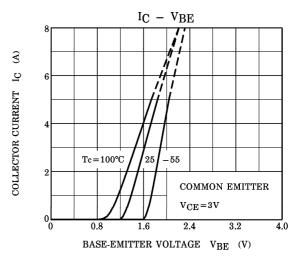


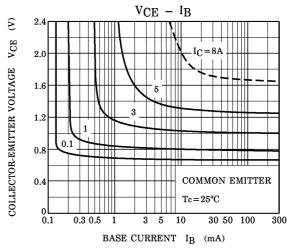
(Note 2) $\ \, \textcircled{1}$ Pulse width adjusted for desired ICP (ICP=5.47A MIN.) $\ \, \textcircled{2}$ E=1/2 L ICP²

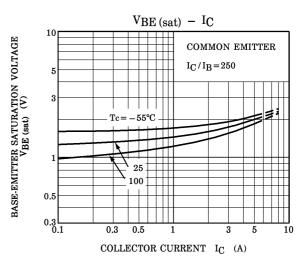




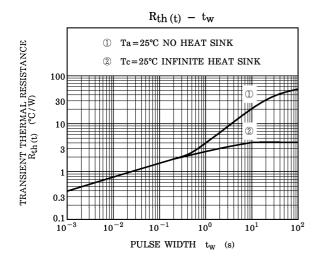


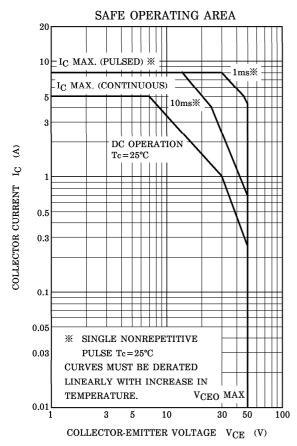


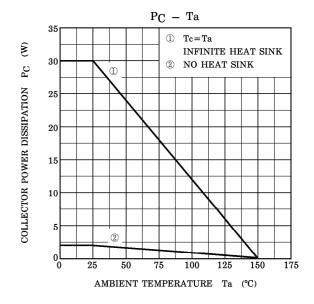




3 2001-11-05







4 2001-11-05

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